FAIRCHILD SEMICONDUCTOR®

May 2013

FDS8813NZ

N-Channel PowerTrench® MOSFET

30V, 18.5A, 4.5mΩ

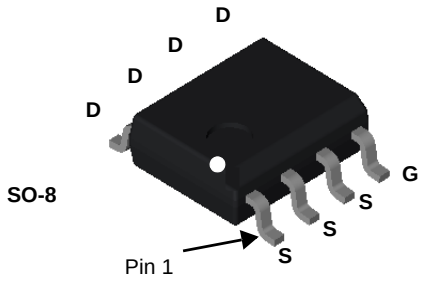
Features

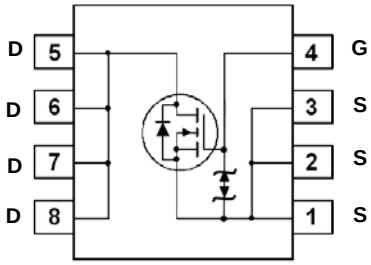
- Max $r_{DS(on)}$ = 4.5mΩ at V_{GS} = 10V, I_D = 18.5A
- Max $r_{DS(on)}$ = 6.0mΩ at V_{GS} = 4.5V, I_D =16A
- HBM ESD protection level of 5.6KV typical (note 3)
- High performance trench technology for extremely low $r_{DS(on)}$
- High power and current handling capability
- RoHS compliant

General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been especially tailored to minimize the on-state resistance.

This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.





MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DS}	Drain to Source Voltage		30	V
V_{GS}	Gate to Source Voltage		±20	V
I_D	Drain Current -Continuous	(Note 1a)	18.5	A
	-Pulsed		74	
E_{AS}	Single Pulse Avalanche Energy	(Note 4)	337	mJ
P_D	Power Dissipation	(Note 1a)	2.5	W
	Power Dissipation	(Note 1b)	1.0	
T_J, T_{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	125	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
FDS8813NZ	FDS8813NZ	13"	12mm	2500 units

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain to Source Breakdown Voltage	I_D = 250μA, V_{GS} = 0V	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250μA, referenced to 25°C		20		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 24V, V_{GS} = 0V			1	μA
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±20V, V_{DS} = 0V			±10	μA
On Characteristics (Note 2)						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250μA	1	1.8	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250μA, referenced to 25°C		-6		mV/°C
$r_{DS(on)}$	Static Drain to Source On Resistance	V_{GS} = 10V, I_D = 18.5A		3.8	4.5	mΩ
		V_{GS} = 4.5V, I_D = 16A		4.7	6.0	
		V_{GS} = 10V, I_D = 18.5A, T_J = 125°C		5.1	6.6	
g_{FS}	Forward Transconductance	V_{DS} = 5V, I_D = 18.5A		74		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 15V, V_{GS} = 0V, f = 1MHz		3115	4145	pF
C_{oss}	Output Capacitance			580	775	pF
C_{rss}	Reverse Transfer Capacitance			345	520	pF
R_g	Gate Resistance	f = 1MHz	0.1	1.8	5.6	Ω
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 15V, I_D = 18.5A, V_{GS} = 10V, R_{GEN} = 6Ω		13	24	ns
t_r	Rise Time			8	16	ns
$t_{d(off)}$	Turn-Off Delay Time			39	63	ns
t_f	Fall Time			7	14	ns
Q_g	Total Gate Charge	V_{GS} = 0V to 10V, V_{DD} = 15V, I_D = 18.5A		55	76	nC
Q_g	Total Gate Charge	V_{GS} = 0V to 5V, V_{DD} = 15V, I_D = 18.5A		28	40	nC
Q_{gs}	Gate to Source Gate Charge	V_{DD} = 15V, I_D = 18.5A		9		nC
Q_{gd}	Gate to Drain “Miller” Charge	V_{DD} = 15V, I_D = 18.5A		10		nC
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Forward Voltage	V_{GS} = 0V, I_S = 2.1A (Note 2)		0.7	1.2	V
t_{rr}	Reverse Recovery Time	I_F = 18.5A, di/dt = 100A/μs		32	47	ns
Q_{rr}	Reverse Recovery Charge			27	41	nC

Notes

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to- ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user’s board design.

a) 50°C/W when mounted on a $1in^2$ pad of 2 oz copper

b) 125°C/W when mounted on a minimum pad .

2. Pulse Test: Pulse Width < 300 us, Duty Cycle < 2%.

3. The diode connected between the gate and source serves only as protection against ESD . No gate overvoltage rating is implied.

4. Starting T_J = 25°C, L = 3mH, I_{AS} = 15A, V_{DD} = 30V, V_{GS} = 10V.

Typical Characteristics T_J = 25°C unless otherwise noted

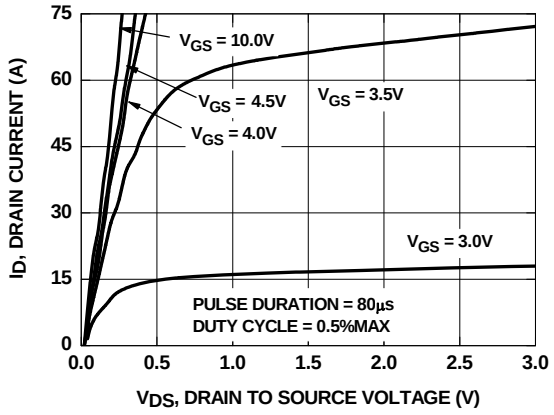


Figure 1. On-Region Characteristics

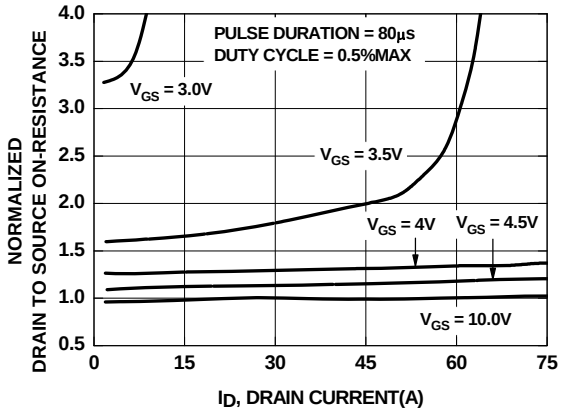


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

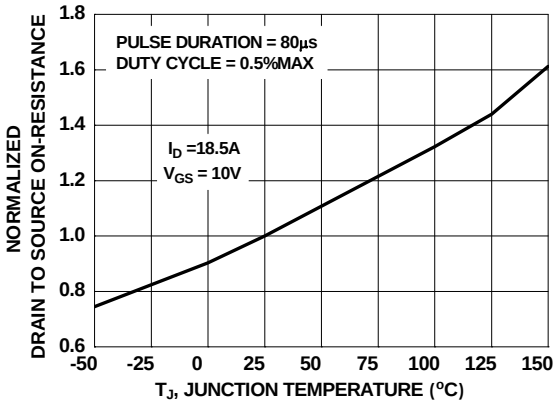


Figure 3. Normalized On-Resistance vs Junction Temperature

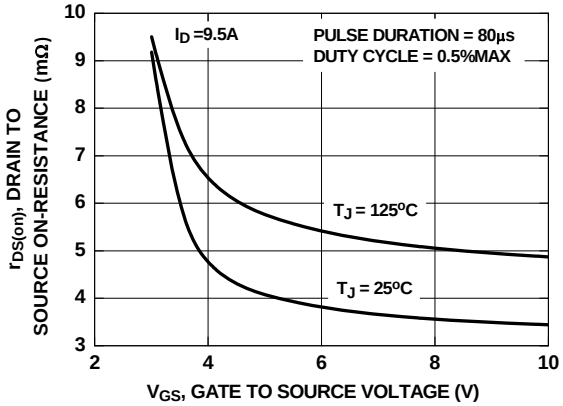


Figure 4. On-Resistance vs Gate to Source Voltage

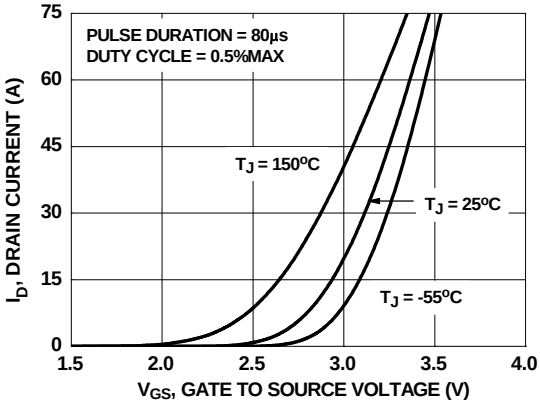


Figure 5. Transfer Characteristics

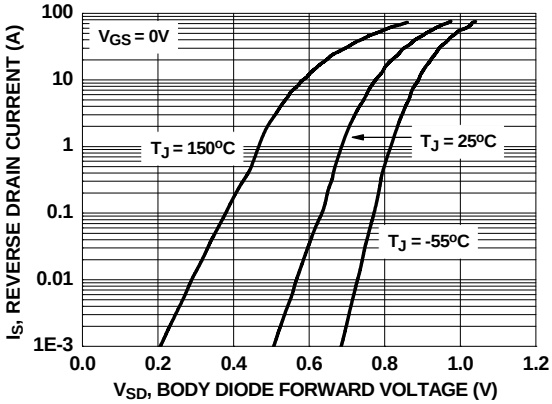


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

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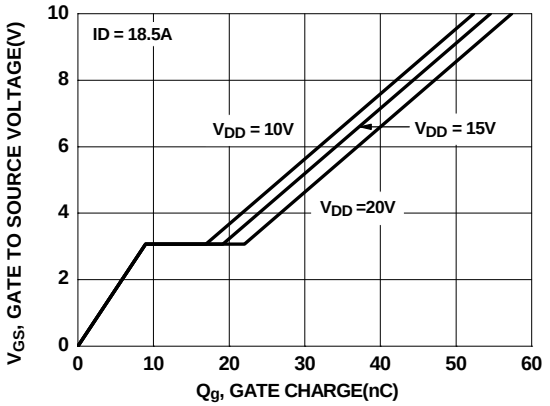

Figure 7. Gate Charge Characteristics

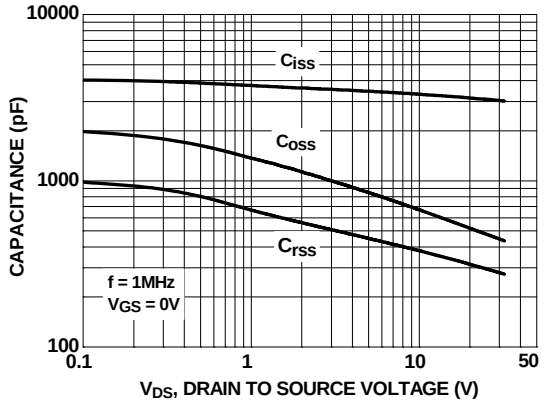

Figure 8. Capacitance vs Drain to Source Voltage

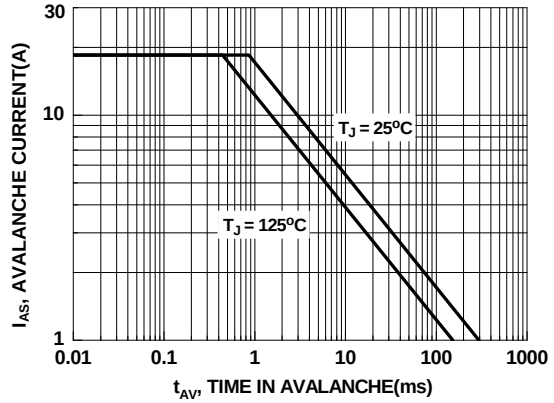

Figure 9. Unclamped Inductive Switching Capability

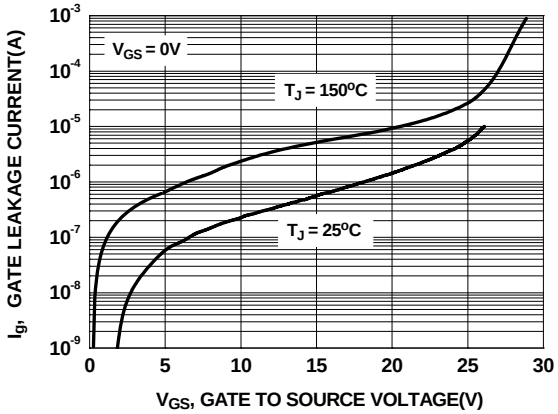

Figure 10. Gate Leakage Current vs Gate to Source Voltage

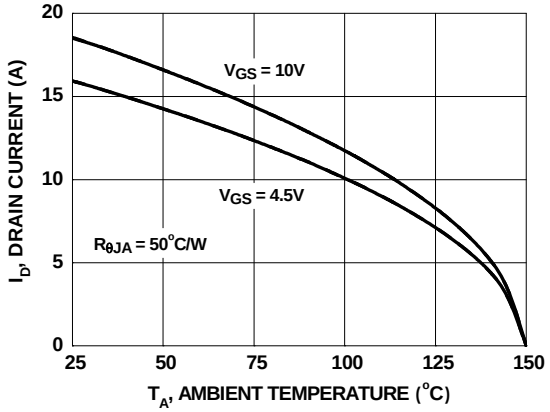

Figure 11. Maximum Continuous Drain Current vs Ambient Temperature

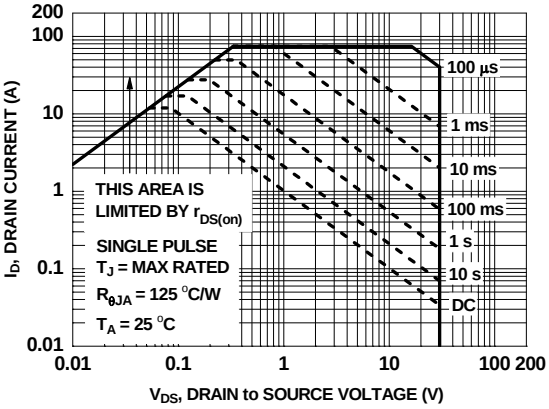

Figure 12. Forward Bias Safe Operating Area

Typical Characteristics T_J = 25°C unless otherwise noted

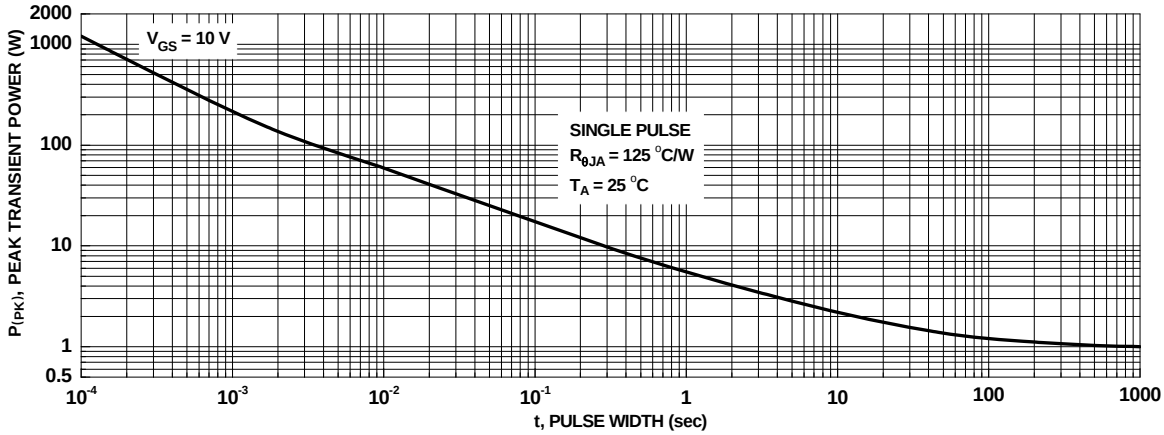

Figure 13. Single Pulse Maximum Power Dissipation

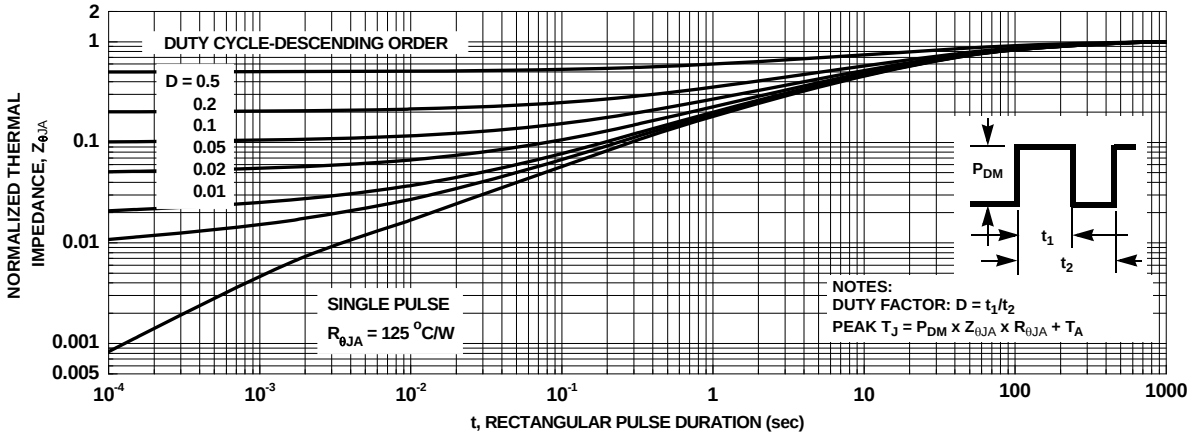

Figure 14. Junction-to-Ambient Transient Thermal Response Curve

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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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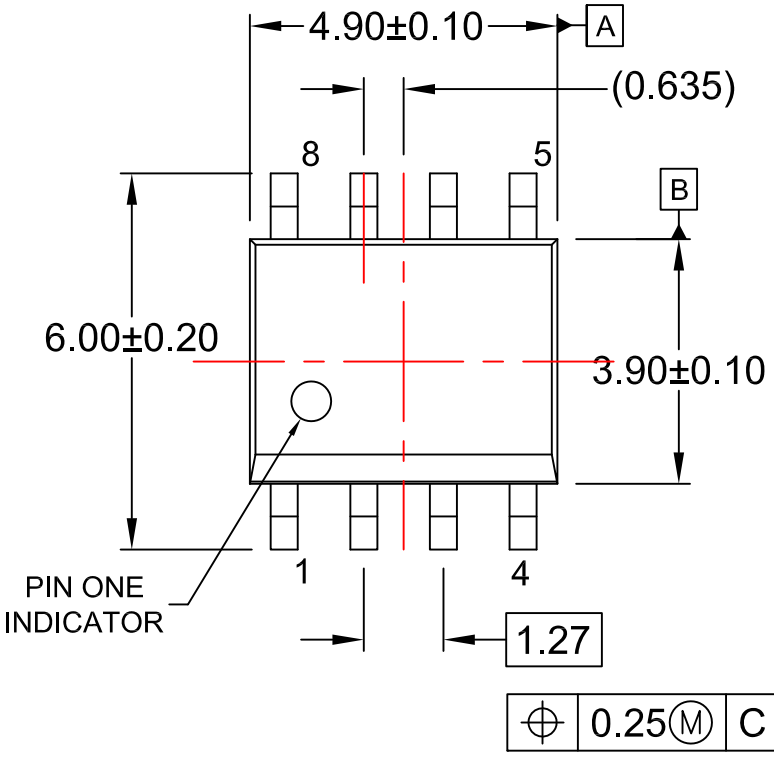

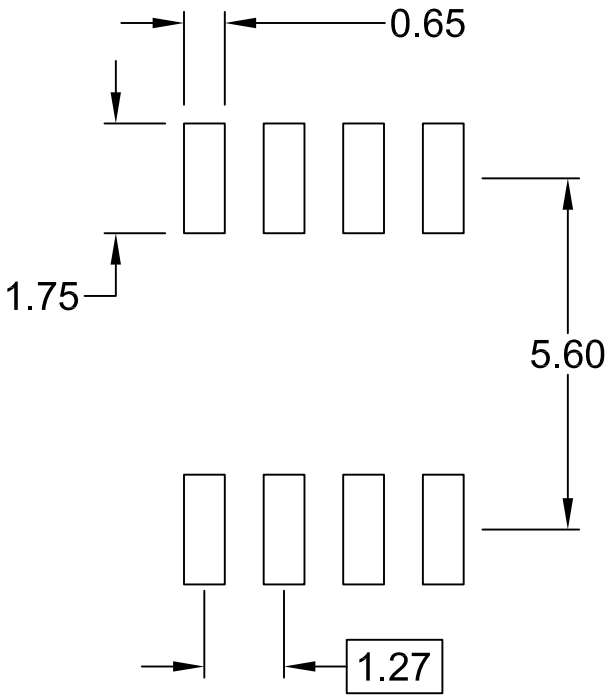

LAND PATTERN RECOMMENDATION

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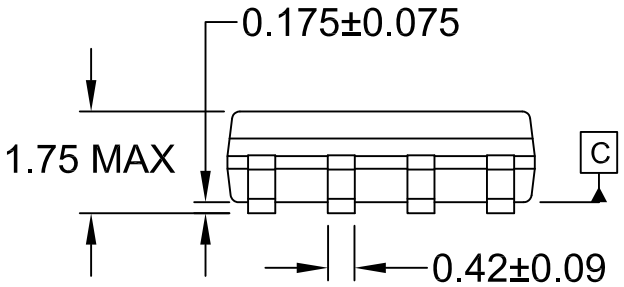

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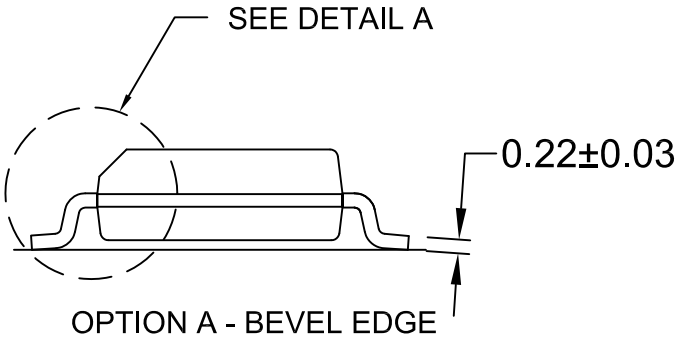
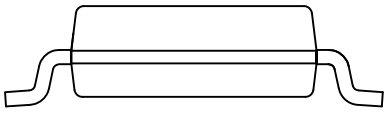
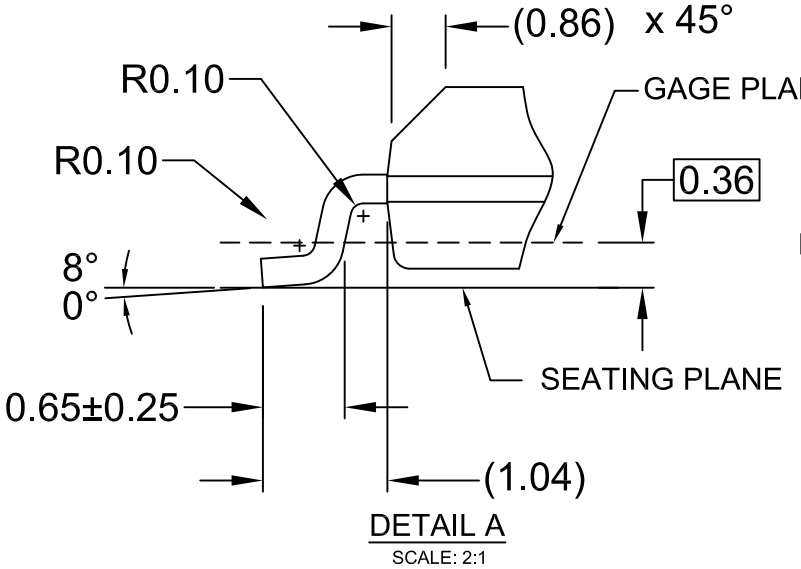


OPTION A - BEVEL EDGE



OPTION B - NO BEVEL EDGE



DETAIL A
SCALE: 2:1

NOTES:

A) THIS PACKAGE CONFORMS TO JEDEC MS-012, VARIATION AA.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
D) LANDPATTERN STANDARD: SOIC127P600X175-8M
E) DRAWING FILENAME: M08Arev16

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MTx®
MVN®
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SuperSOT™-6
SuperSOT™-8
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Sync-Lock™
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TinyBoost®
TinyBuck®
TinyCalc™
TinyLogic®
TINYOPTO™
TinyPower™
TinyPWM™
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  Minhang District, Shanghai , China

- ### Sales :

  Direct +86 (21) 6401-6692

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